To our customers,

Old Company Name in Catalogs and Other Documents

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Renesas Electronics website: http://www.renesas.com

April 1st, 2010
Renesas Electronics Corporation

Issued by: Renesas Electronics Corporation (http://www.renesas.com)

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RENESAS

MOS FIELD EFFECT TRANSISTOR

μPA1918

P-CHANNEL MOS FIELD EFFECT TRANSISTOR FOR SWITCHING

DESCRIPTION

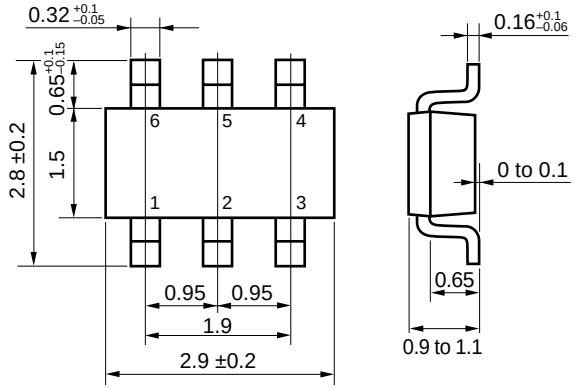
The μPA1918 is a switching device, which can be driven directly by a 4.0 V power source.

This device features a low on-state resistance and excellent switching characteristics, and is suitable for applications such as power switch of portable machine and so on.

FEATURES

- 4.0 V drive available
- Low on-state resistance
  $R_{DS(on)1}$ = 143 mΩ MAX. (V_{GS} = –10 V, I_D = –2.0 A)
  $R_{DS(on)2}$ = 179 mΩ MAX. (V_{GS} = –4.5 V, I_D = –2.0 A)
  $R_{DS(on)3}$ = 190 mΩ MAX. (V_{GS} = –4.0 V, I_D = –2.0 A)

PACKAGE DRAWING (Unit: mm)



1, 2, 5, 6 : Drain
3 : Gate
4 : Source

ORDERING INFORMATION

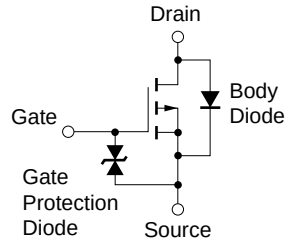
PART NUMBER	PACKAGE
μPA1918TE	SC-95 (Mini Mold Thin Type)

Marking: TS

ABSOLUTE MAXIMUM RATINGS (T_A = 25°C)

Drain to Source Voltage (V_{GS} = 0 V)	V_{DSS}	–60	V
Gate to Source Voltage (V_{DS} = 0 V)	V_{GSS}	∓20	V
Drain Current (DC) (T_A = 25°C)	$I_{D(DC)}$	∓3.5	A
Drain Current (pulse) **Note1**	$I_{D(pulse)}$	∓14	A
Total Power Dissipation	P_{T1}	0.2	W
Total Power Dissipation **Note2**	P_{T2}	2.0	W
Channel Temperature	T_{ch}	150	°C
Storage Temperature	T_{stg}	–55 to +150	°C

EQUIVALENT CIRCUIT



Notes 1. PW ≤ 10 μs, Duty Cycle ≤ 1%

2. Mounted on FR-4 board, t ≤ 5 sec.

Remark The diode connected between the gate and source of the transistor serves as a protector against ESD. When this device actually used, an additional protection circuit is externally required if a voltage exceeding the rated voltage may be applied to this device.

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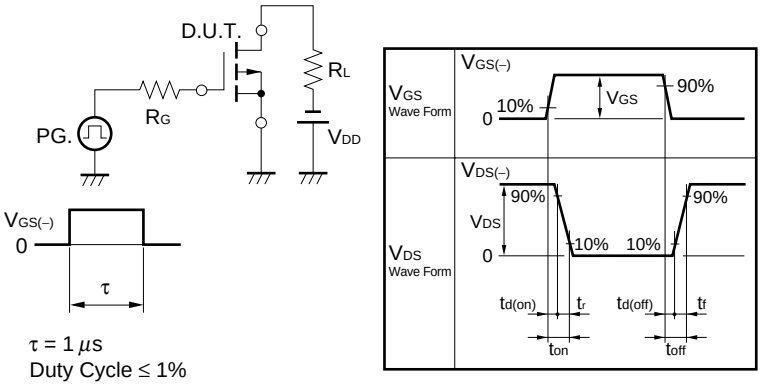
Date Published June 2002 NS CP(K)
Printed in Japan

ELECTRICAL CHARACTERISTICS (T_A = 25°C)

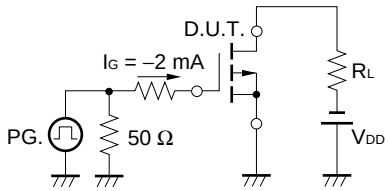
CHARACTERISTICS	SYMBOL	TEST CONDITIONS	MIN.	TYP.	MAX.	UNIT
Zero Gate Voltage Drain Current	I_{DSS}	V_{DS} = –60 V, V_{GS} = 0 V			–1.0	μA
Gate Leakage Current	I_{GSS}	V_{GS} = ∓20 V, V_{DS} = 0 V			∓10	μA
Gate Cut-off Voltage	$V_{GS(off)}$	V_{DS} = –10 V, I_D = –1.0 mA	–1.5	–1.9	–2.5	V
Forward Transfer Admittance	$\|y_{fs}\|$	V_{DS} = –10 V, I_D = –2.0 A	3.0	6.2		S
Drain to Source On-state Resistance	$R_{DS(on)1}$	V_{GS} = –10 V, I_D = –2.0 A		114	143	mΩ
	$R_{DS(on)2}$	V_{GS} = –4.5 V, I_D = –2.0 A		134	179	mΩ
	$R_{DS(on)3}$	V_{GS} = –4.0 V, I_D = –2.0 A		142	190	mΩ
Input Capacitance	C_{iss}	V_{DS} = –10 V		666		pF
Output Capacitance	C_{oss}	V_{GS} = 0 V		120		pF
Reverse Transfer Capacitance	C_{rss}	f = 1.0 MHz		58		pF
Turn-on Delay Time	$t_{d(on)}$	V_{DD} = –30 V, I_D = –2.0 A		12		ns
Rise Time	t_r	V_{GS} = –10 V		5		ns
Turn-off Delay Time	$t_{d(off)}$	R_G = 10 Ω		58		ns
Fall Time	t_f			27		ns
Total Gate Charge	Q_G	V_{DD} = –48 V		12		nC
Gate to Source Charge	Q_{GS}	V_{GS} = –10 V		1.5		nC
Gate to Drain Charge	Q_{GD}	I_D = –3.5 A		3.5		nC
Body Diode Forward Voltage	$V_{F(S-D)}$	I_F = 3.5 A, V_{GS} = 0 V		0.87		V

TEST CIRCUIT 1 SWITCHING TIME



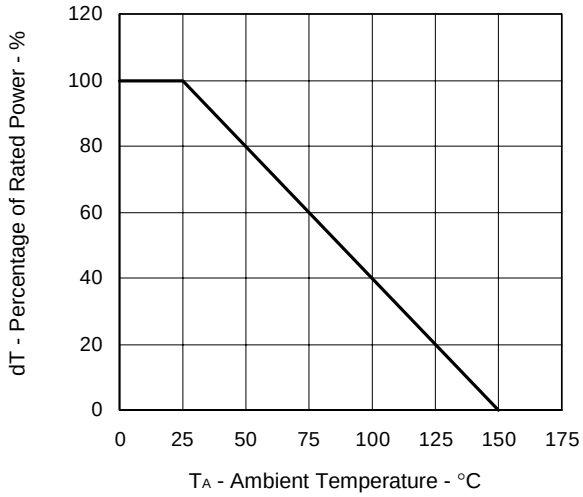
τ = 1 μs
Duty Cycle ≤ 1%

TEST CIRCUIT 2 GATE CHARGE

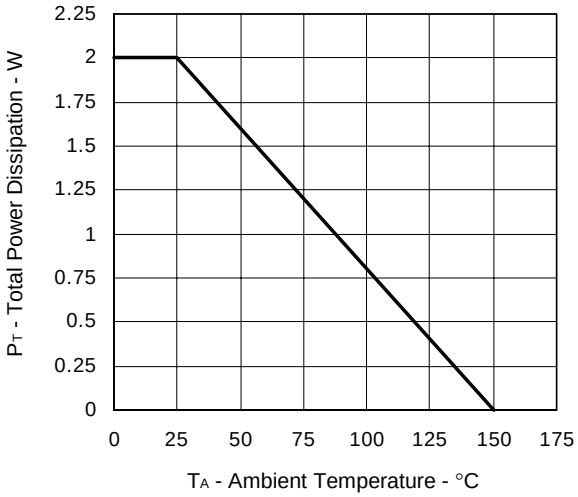


TYPICAL CHARACTERISTICS (T_A = 25°C)

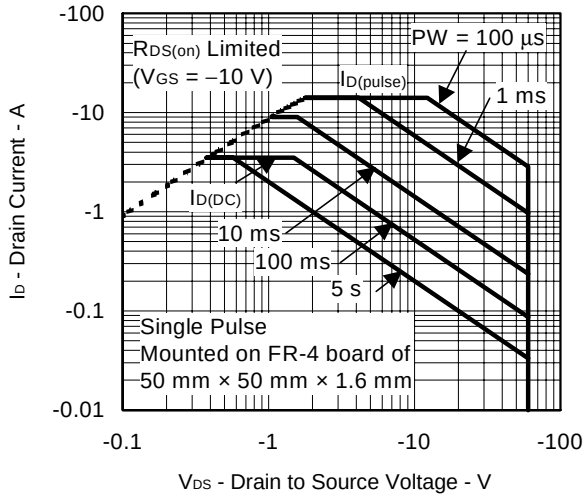
DERATING FACTOR OF FORWARD BIAS SAFE OPERATING AREA



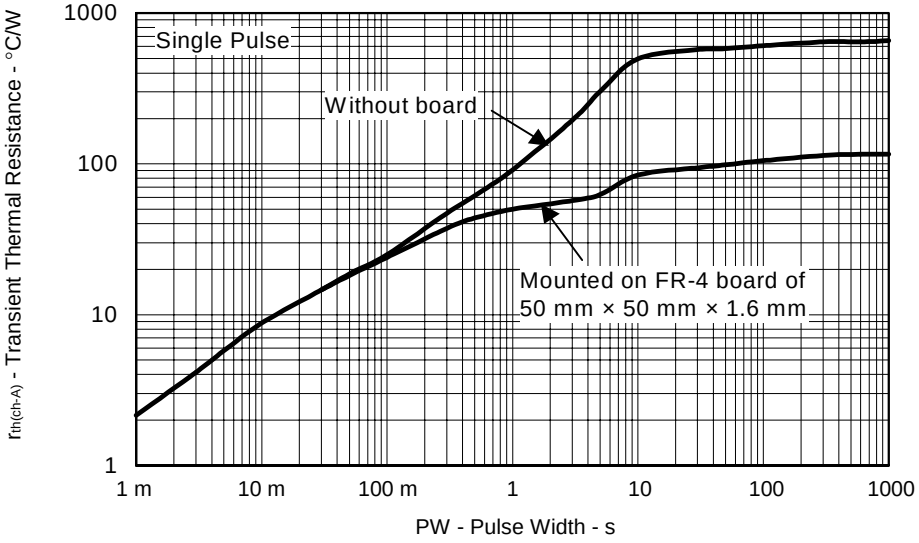
TOTAL POWER DISSIPATION vs. AMBIENT TEMPERATURE



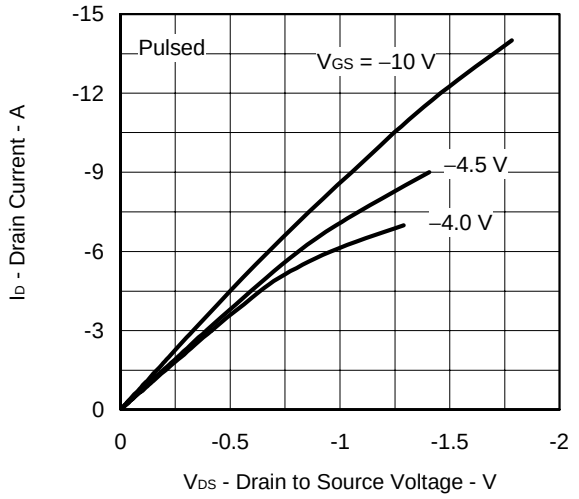
FORWARD BIAS SAFE OPERATING AREA



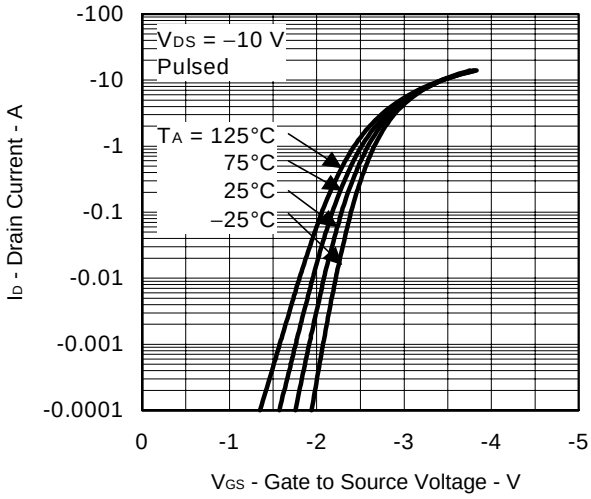
TRANSIENT THERMAL RESISTANCE vs. PULSE WIDTH



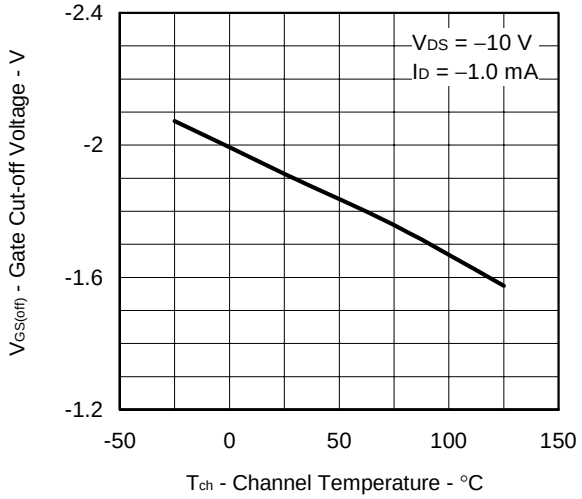
DRAIN CURRENT vs.
DRAIN TO SOURCE VOLTAGE



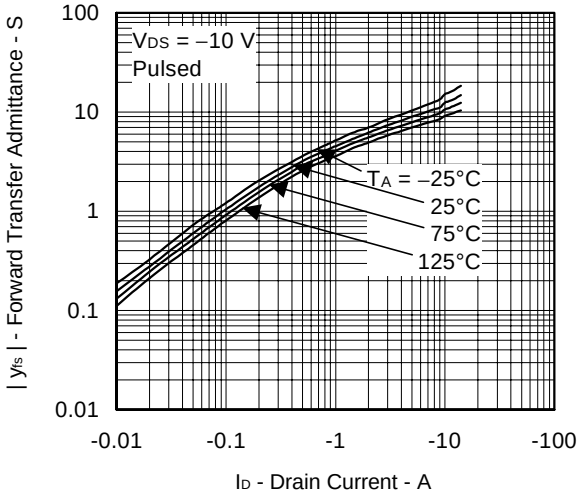
FORWARD TRANSFER CHARACTERISTICS



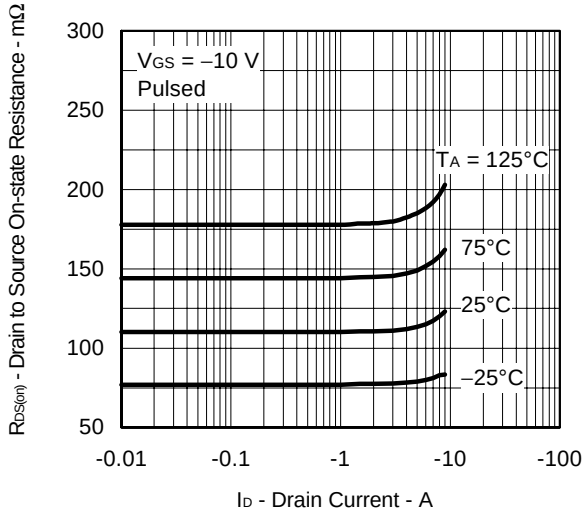
GATE CUT-OFF VOLTAGE vs.
CHANNEL TEMPERATURE



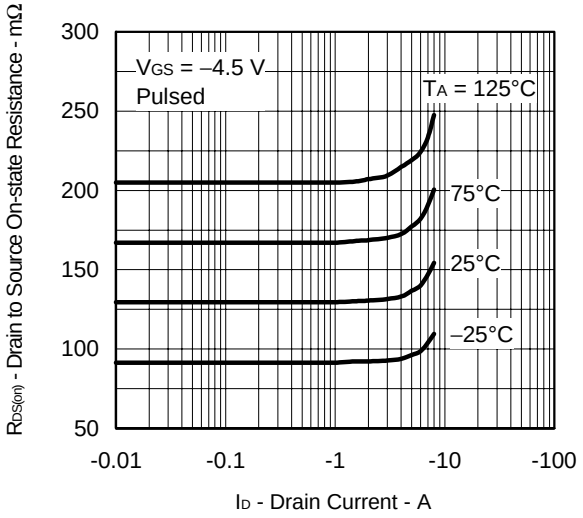
FORWARD TRANSFER ADMITTANCE vs.
DRAIN CURRENT



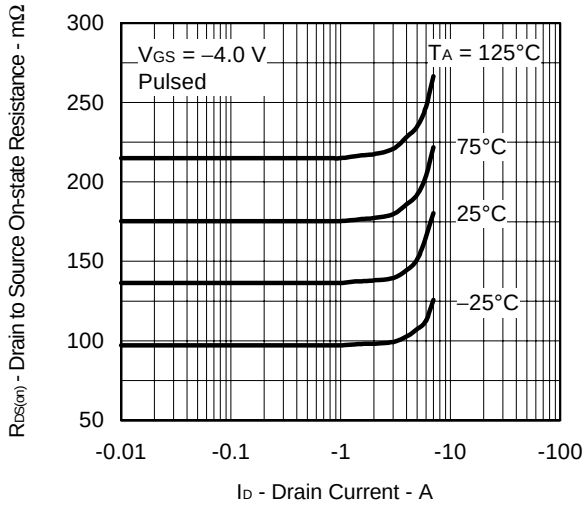
DRAIN TO SOURCE ON-STATE RESISTANCE vs.
DRAIN CURRENT



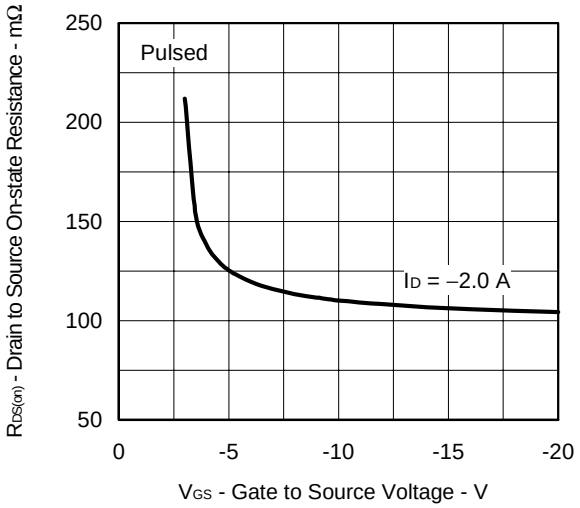
DRAIN TO SOURCE ON-STATE RESISTANCE vs.
DRAIN CURRENT



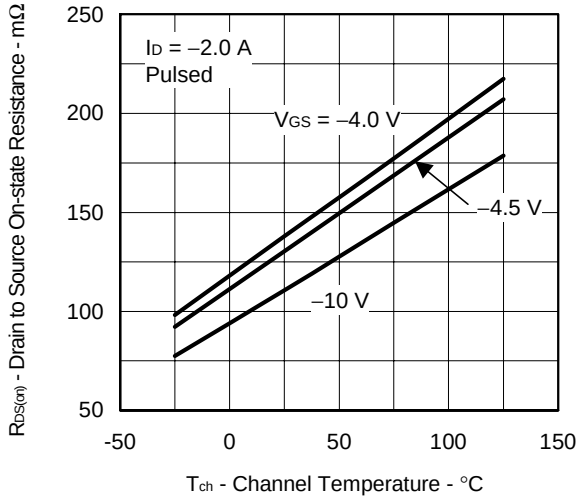
DRAIN TO SOURCE ON-STATE RESISTANCE vs. DRAIN CURRENT



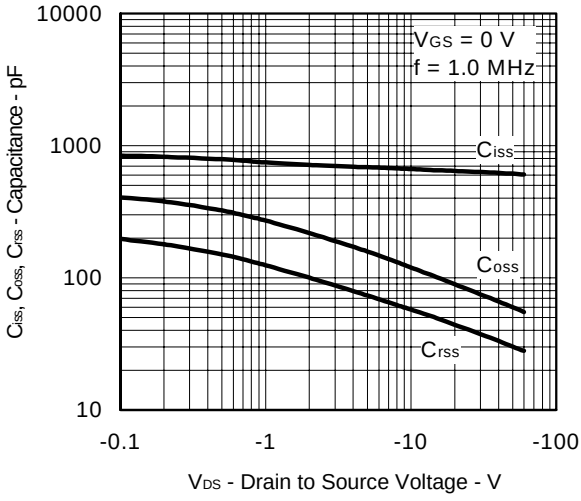
DRAIN TO SOURCE ON-STATE RESISTANCE vs. GATE TO SOURCE VOLTAGE



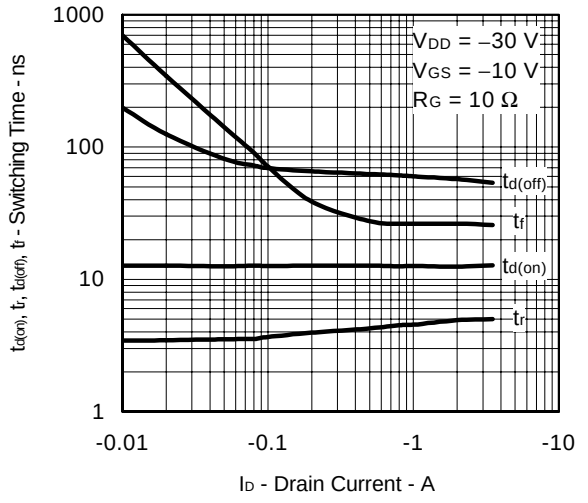
DRAIN TO SOURCE ON-STATE RESISTANCE vs. CHANNEL TEMPERATURE



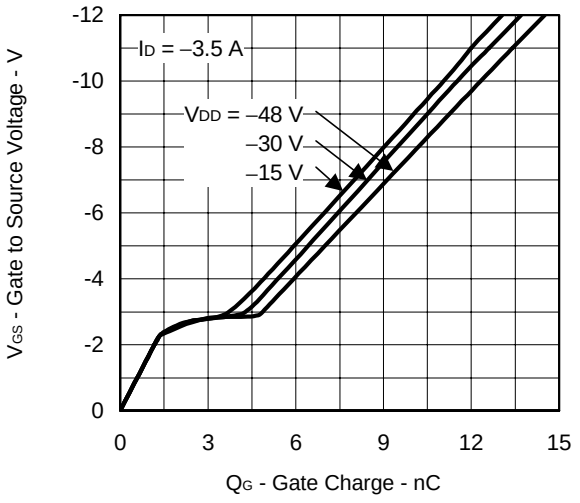
CAPACITANCE vs. DRAIN TO SOURCE VOLTAGE



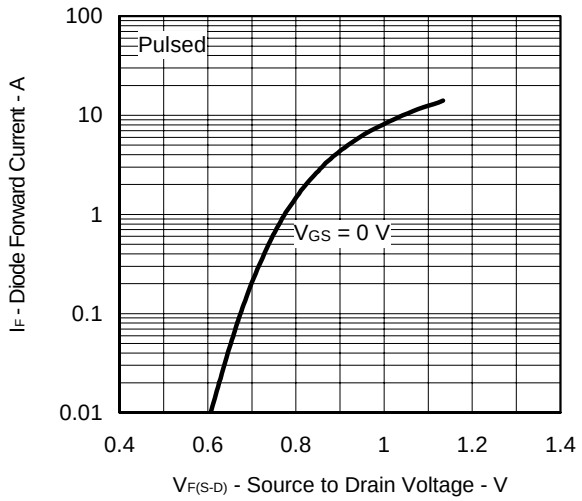
SWITCHING CHARACTERISTICS



DYNAMIC INPUT/OUTPUT CHARACTERISTICS



SOURCE TO DRAIN DIODE FORWARD VOLTAGE



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